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### **Resonance Kondo tunneling through a Double Quantum Dot at finite bias**

# Outline

- Introduction: Kondo effect in Quantum Dots
- SO(4) Spin-Rotator Model
- RG Equations and conductance
- Decoherence effects
- Basic inequalities
- Conclusions

M.N.Kiselev, K.Kikoin and L.W.Molenkamp, PRB 68, 155323 (2003)

## Quantum dot devices



(a) A quantum dot can be defined by applying voltages to the surrounding gate electrodes (yellow). The tunnelling between the dot and the external electrodes (top left) is controlled by changing the voltages on the lower-left and lower-right gates. This coupling defines the lifetime broadening,  $\Gamma$ , of the quantum state in the dot. The number of electrons and the energy levels are tuned by the voltage on the lower-central gate. The puddle of electrons (confined region) is about 0.5 microns in diameter. (b) Quantum dots can be placed in both arms of a two-slit interference device. Such a device has been used to investigate whether this scattering destroys the interference pattern. (c) Three quantum dots that have been used to compare the Kondo effect for singlet, doublet and triplet spin-states.

L.Kouwenhoven and L.Glazman, Physics World 2001



(a) The conductance (y-axis) as a function of the gate voltage, which changes the number of electrons, *N*, confined in a quantum dot. When an even number of electrons is trapped, the conductance decreases as the temperature is lowered from 1 K (orange) to 25 mK (light blue). This behaviour illustrates that there is no Kondo effect when *N* is even. The opposite temperature dependence is observed for an odd number of electrons, i.e. when there is a Kondo effect. (b) The conductance for N + 1 electrons at three different fixed gate voltages indicated by the coloured arrows in (a). The Kondo temperature,  $T_{R^2}$  for the different gate voltages can be calculated by fitting the theory to the data. (c) When the same data are replotted as a function of temperature divided by the respective Kondo temperature, the different curves lie on top of each other, illustrating that electronic transport in the Kondo regime is described by a universal function that depends only on  $T/T_{R}$ .

### Kondo effect in Quantum dots



L.Kouwenhoven and L.Glazman, Physics World 2001



(a) By manipulating cobalt atoms on a copper surface. Don Eigler and colleagues at IBM have placed a single cobalt atom at the focal point of an ellipse built from other cobalt atoms (bottom). The density of states (top) measured at this focus reveals the Kondo resonance (left peak). However, elliptical confinement also gives rise to a second smaller Kondo resonance at the other focal point (right) even though there is no cobalt atom there. (b) Meanwhile, Mike Crommie and co-workers have measured two Kondo resonances produced by two separate cobalt atoms on a gold surface (top). When two cobalt atoms are moved close together using an STM, the mutual interaction between them causes the Kondo effect to vanish (data not shown).

# **Double Quantum Dot**

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#### **Resonant Tunneling Through Two Discrete Energy States**

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We observed new type of Lorentzian-shaped resonances in the current through two coupled quantum dots with tunable barriers. We show that the resonances occur when the energy of two discrete states match. Their widths can be as small as  $5 \ \mu eV$  and are only determined by the lifetime of the discrete energy states, independent of the reservoir temperature. The achieved energy resolution makes it possible to observe a small asymmetric deviation from the Lorentzian line shape, which we attribute to inelastic tunnel processes.





FIG. 2. *I-V* curve of the double dot, showing sharp resonances in the current when two 0D states line up. Upper inset: *I-V* curve of dot I. Lower inset: *I-V* curve of dot II. Both insets show a suppression of the current at low voltages due to the Coulomb blockade and a stepwise increase of the current due to the discrete energy spectrum of the dot.



# **Parallel and serial DQD**









R.Lopez, R.Aguado, and G.Platero, PRL 2002

### **Exotic symmetries**

#### SU(4) Fermi liquid



FIG. 1. Upper part: Schematics of the DD device. Lower part: Virtual process leading to 'spin-flip assisted tunneling' as described in Eq. (4)

#### L.Borda,Gzarand,W.Hofstetter,B.I.Halperin, and Jan von Delft, PRL 2003

#### Quantum Phase transition



W.Hofstetter and H.Schoeller, PRL 2002

#### Singlet-triplet transition in a magnetic field



FIG. 1. (a) The spinless ground state of the dot with  $\mathcal{N}$  = even electrons. (b) Excited state which has  $S^z = 1$ . States (a) and (b) differ by adding a spin-down or spin-up electron accordingly to the state  $|\Omega\rangle$  of  $\mathcal{N} - 1$  electrons in the dot, shown at (c). The states (a) and (b) are denoted as  $|\downarrow\rangle$  and  $|\uparrow\rangle$  in (5).



FIG. 4. Position of the peaks of differential conductance at  $(eV_{\rm DC}, \Delta)$  plane. The dashed lines correspond to  $eV_{\rm DC} = \pm \Delta$ . The angle  $\vartheta \approx \chi/2 = \eta \nu J_z/4 \ll 1$  can be either positive or negative, depending on the sign of the nonuniversal parameter  $\eta$ .



FIG. 1. Typical picture of the singlet-triplet transition in the ground state of a quantum dot.



FIG. 2. Low-energy states of a spin-degenerate quantum dot in magnetic field.

M.Pustilnik and L.Glazman, PRL 2000, PRB 2001



L.W.Molenkamp et al, PRL 1995

Hamiltonian for DQD model Anderson Hamiltonian  $H_{d} = E_{S} |S\rangle\langle S| + \sum_{\mu} E_{T} |T\mu\rangle\langle T\mu| \equiv \sum_{\Lambda \in S} E_{\Lambda} X^{\Lambda\Lambda}$  $\Lambda = S.T \mu$  $H_{b} + H_{t} = \sum \varepsilon_{k\alpha} c_{k\alpha\sigma}^{\dagger} c_{k\alpha\sigma} + \sum \sum (W_{\sigma}^{\Lambda\lambda} c_{k\alpha\sigma}^{\dagger} X^{\lambda\Lambda} + H.c.)$  $k\alpha\sigma$ **Spin-Rotator** Hamiltonian  $H_{\text{int}} = \sum \left[ (J_{aa}^{TT} \overline{S} + J_{aa}^{ST} \overline{P}) \cdot \overline{S} + J_{aa}^{SS} X^{SS} n \right]$ 





SO(4) algebra of Spin-Rotator Permutations  $\begin{bmatrix} S_j, S_k \end{bmatrix} = i\varepsilon_{jkl}S_l \qquad \begin{bmatrix} P_j, P_k \end{bmatrix} = i\varepsilon_{jkl}S_l \qquad \begin{bmatrix} S_j, P_k \end{bmatrix} = i\varepsilon_{jkl}P_l$ **Representation in terms of Hubbard operators**  $S^{+} = \sqrt{2} \left( X^{10} + X^{0-1} \right) \quad S^{-} = \sqrt{2} \left( X^{01} + X^{-10} \right) \quad S^{+} = \left( X^{11} - X^{-1-1} \right)$  $P^{+} = \sqrt{2} \left( X^{1S} - X^{S-1} \right) P^{-} = \sqrt{2} \left( X^{S1} - X^{-1S} \right) P^{z} = \left( X^{0S} + X^{S0} \right)$ **Casimir** operators  $S^{2} + P^{2} = 3$  $S \bullet P = 0$  $S^2 = 2 - 2 \cdot X^{SS}$   $P^2 = 1 + 2 \cdot X^{SS}$ 

![](_page_14_Figure_0.jpeg)

# **Green's functions**

 $H_{\text{int}} = \sum_{kk',\alpha\alpha'=L,R} J^{S}_{\alpha\alpha'} f^{+}_{s} f_{s} c^{+}_{k\alpha\sigma} c_{k'\alpha'\sigma} + \sum_{kk',\alpha\alpha'=L,R} \left[ J^{T}_{\alpha\alpha'} \widehat{S}^{d}_{\lambda\lambda'} + J^{ST}_{\alpha\alpha'} \widehat{P}^{d}_{\lambda\lambda'} \right] f^{+}_{\Lambda} f_{\Lambda'} c^{+}_{k\alpha\sigma} \widehat{\tau}^{d}_{\sigma\sigma'} c_{k'\alpha'\sigma'}$ 

Fermi - representation of SQ(4) group

$$S^{+} = \sqrt{2} \left( f_{0}^{+} f_{-1} + f_{1}^{+} f_{0} \right), \quad S^{-} = \sqrt{2} \left( f_{-1}^{+} f_{0} + f_{0}^{+} f_{1} \right), \quad S^{z} = \left( f_{1}^{+} f_{1} - f_{-1}^{+} f_{-1} \right),$$
$$P^{+} = \sqrt{2} \left( f_{1}^{+} f_{s} - f_{s}^{+} f_{-1} \right), \quad P^{-} = \sqrt{2} \left( f_{s}^{+} f_{1} - f_{-1}^{+} f_{s} \right), \\P^{z} = - \left( f_{0}^{+} f_{s} + f_{s}^{-} f_{s}^{+} f_{-1} \right),$$

Electrons in the leads

 $G_{L,R}^{0}(k,\varepsilon_{n}) = \frac{1}{i\varepsilon_{n} - \varepsilon(k) + \mu_{L,R}}$  $D_s^0(\omega_n) = \frac{1}{i\varepsilon_n - E_s} \quad \text{singlet}$  $D_t^0(\omega_n) = \frac{1}{i\omega_n - E_T} \quad \text{triplet}$ 

Two-electron states in the dot

![](_page_16_Figure_0.jpeg)

M.Kiselev and R.Oppermann, PRL 2000

Real-time SF approach  

$$\begin{aligned}
G_{0,\sigma}(\varepsilon) &= G_{0,\sigma}^{R}(\varepsilon) \begin{pmatrix} 1-n_{\varepsilon}^{S} & -n_{\varepsilon}^{S} \\ 1-n_{\varepsilon}^{S} & -n_{\varepsilon}^{S} \end{pmatrix} - G_{0,\sigma}^{A}(\varepsilon) \begin{pmatrix} -n_{\varepsilon}^{S} & -n_{\varepsilon}^{S} \\ 1-n_{\varepsilon}^{S} & 1-n_{\varepsilon}^{S} \end{pmatrix} \\
&= \frac{1-i\sigma_{y}}{\sqrt{2}} \sigma_{z} G \frac{1+i\sigma_{y}}{\sqrt{2}} = \begin{pmatrix} G^{R} & G^{K} \\ 0 & G^{A} \end{pmatrix} \\
&= \frac{1}{\exp(i\pi/(2S+1))\exp(\varepsilon/T)+1} C_{\tau} & \Psi & \Psi_{z} \\
&= \frac{1}{\exp(i\pi/(2S+1))\exp(\varepsilon/T)} & S = \frac{1}{2} \\
&= \frac{1}{\exp(i\pi/(2S+1))\exp(\varepsilon/T)} & S = \frac{1}{2}$$

![](_page_18_Figure_0.jpeg)

![](_page_19_Figure_0.jpeg)

![](_page_20_Figure_0.jpeg)

# **Solutions**

$$\frac{dJ_{LL,\pm}^{ST}}{d\ln D} = -\frac{1}{2} v \left( J_{LL,z}^{ST} J_{LL,\pm}^{T} + J_{LL,\pm}^{ST} J_{LL,z}^{T} \right),$$

$$\frac{dJ_{LL,z}^{ST}}{d\ln D} = -v J_{LL,\pm}^{ST} J_{LL,\pm}^{T},$$

$$\frac{dJ_{LR}^{T}}{d\ln D} = -v J_{LL}^{T} J_{LR}^{T},$$

$$\frac{dJ_{LR}^{ST}}{d\ln D} = -v J_{LL}^{T} J_{LR}^{T},$$

$$\frac{dJ_{LR}^{ST}}{d\ln D} = -v J_{LL}^{T} J_{LR}^{T},$$

$$\frac{dJ_{LR}^{ST}}{d\ln D} = -\frac{1}{2} v \left( J_{LL,\pm}^{ST} J_{LR,\pm}^{TS} + \frac{1}{2} J_{LL,z}^{ST} J_{LR,z}^{TS} \right).$$

$$T_{K} = D \exp \left( -\frac{1}{v J_{L}^{T}} \right)$$

$$J_{LR}^{S} = J_{0}^{S} - \frac{3}{4} \nu \left(J_{0}^{ST}\right)^{2} \frac{\ln(D/T)}{1 - \nu J_{0}^{T} \ln(D/T)}$$

![](_page_22_Figure_0.jpeg)

![](_page_23_Figure_0.jpeg)

![](_page_24_Figure_0.jpeg)

![](_page_25_Figure_0.jpeg)

# **Basic inequalities**

 $\{eV_{dc}, eV_{dot}, eV_{ac}\} < \{E_d, U - E_d\}$  Validity of SW transformation

 $T_{K} \ll eV \leq \delta \ll D$  Absence of Kondo effect in equilibrium

 $eV - \delta \ll T_{K}$  Condition of Kondo resonance in nonequilibrium

 $\delta \left(\frac{\delta}{D}\right)^2 \ll T_K \ll \delta$  DC decoherence rate effects are irrelevant

 $h/\tau_d \ll T_k$  AC decoherence rate effects are irrelevant

# Conclusions

• resonance Kondo tunneling through DQD with even occupation number and singlet ground state can be induced by external electric field which compensates the energy of singlet/triplet excitation

 decoherence effects associated with the relaxation of triplet state are controllable by tuning of the singlet/triplet splitting

 electric field induced Kondo effect can be observed in DQD in parallel geometry